Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

**Overall Length:** 

0.450 inches

## **Overall Diameter:**

0.667 inches

### **Mounting Facility Quantity:**

1

# Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

**Overall Width Across Flats:** 

Between 0.667 inches and 0.687 inches

Thread Size:

# 0.250 inches

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

4.1 breakdown voltage, dc

## Current Rating Per Characteristic:

12400.00 milliamperes repetitive peak forward current

### Power Rating Per Characteristic:

50.0 watts total power dissipation

## Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius case

### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

### **Thread Series Designator:**

Unf

# Terminal Type And Quantity:

1 threaded stud and 1 tab, solder lug

# **Specification Data:**

81349-mil-s-19500/358 government specification

Shelf Life:

N/a

Unit Of Measure:

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### Demilitarization:

No

Fiig:

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